

# Master / Semester Thesis

## Unipolar Resistive Switching in Valence Change Memory Cells

### Short Description

The goal of the project is to simulate and gain a deeper understanding of unipolar resistive switching in oxide-based memristors by combining different methods, such as Density Functional Theory (DFT), Kinetic Monte Carlo, and quantum transport simulations. The student will use an already established simulation protocol (Fig. 1a) to calculate necessary parameters for systems that exhibit unipolar switching. The main tasks of the projects will be to simulate unipolar I-V characteristics, to explain the physical process that led to it, and to provide some guidelines for enhancing the performances of such devices.

### The Big Picture

Valence-change memory (VCM) cells based on oxides have attracted significant interest in recent years due to their potential applications in non-volatile memory devices and neuromorphic computing. Most VCMs exhibit bipolar switching governed by the formation and the rupture of a conductive filament made of oxygen vacancies. Some devices are known to exhibit unipolar switching (Fig. 1b), which is believed to be induced by Joule heating. However, a detailed atomistic picture of the underlying mechanisms remains incomplete.

### Type of Work

The project will consist of:

- A literature review on oxide-based memristors, DFT calculations, KMC simulations, and quantum transport calculations (10 %),
- Performing DFT, KMC, and quantum transport calculations (60 %)
- Coding, data post-processing and analyzing, and report writing (30 %)

### Prerequisites

We are seeking a candidate with a strong interest in nanoelectronics and materials science, with experience with Python and C++, and familiarity with Linux-based operating systems.

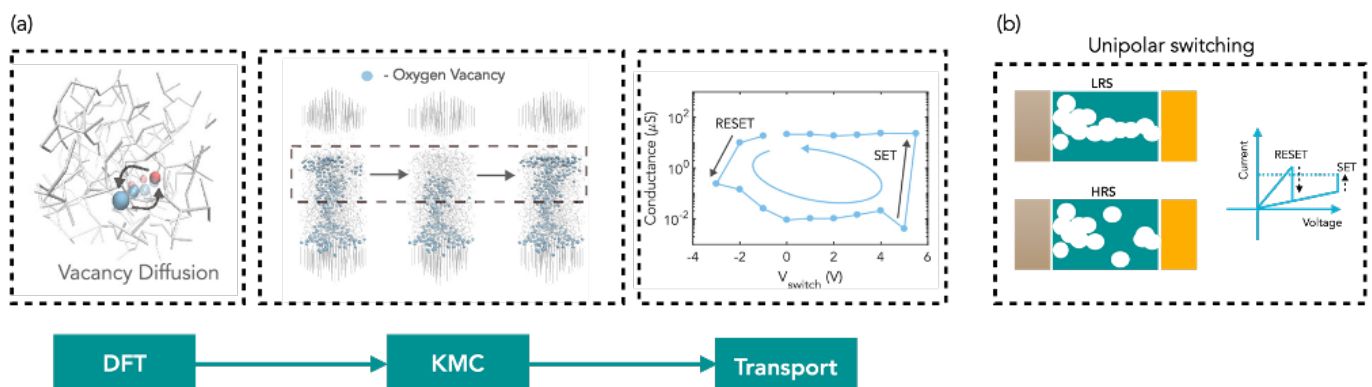


Fig. 1 (a) The simulation protocol consisting of DFT, KMC, and quantum transport calculations. The images are adapted from [1]. (b) The schematic description of unipolar resistive switching.

# Master / Semester Thesis

## References

[1] Manasa Kaniselvan, Mathieu Luisier, and Marko Mladenović *ACS Nano* 2023 **17** (9), 8281-8292

## Status: Available

Looking for 1 Semester/ Master student

Interested candidates please contact: Dr. Marko Mladenović [mladenovic@iis.ee.ethz.ch](mailto:mladenovic@iis.ee.ethz.ch)

ETH Professor: Prof. Mathieu Luisier [mluisier@iis.ee.ethz.ch](mailto:mluisier@iis.ee.ethz.ch)